LMV1012

LMV1012 Analog Series: Pre-Amplified IC's for High Gain 2-Wire Microphones

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LMV1012 Analog Series: Pre-Amplified IC's for High Gain 2-Wire Microphones

General Description

The LMV1012 is an audio amplifier series for small form factor electret microphones. This 2-wire portfolio is designed to replace the JFET amplifier currently being used. The LMV1012 series is ideally suited for applications requiring high signal integrity in the presence of ambient or RF noise, such as in cellular communications. The LMV1012 audio amplifiers are guaranteed to operate over a 2.2V to 5.0V supply voltage range with fixed gains of 7.8 dB, 15.6 dB, 20.9 dB, and 23.8 dB. The devices offer excellent THD, gain accuracy and temperature stability as compared to a JFET microphone.

The LMV1012 series enables a two-pin electret microphone solution, which provides direct pin-to-pin compatibility with the existing JFET market.

The devices are offered in extremely thin space saving 4-bump micro SMD packages. The LMV1012XP is designed for 1.0 mm canisters and thicker ECM canisters. These extremely miniature packages are designed for electret condenser microphones (ECM) form factor.

Features

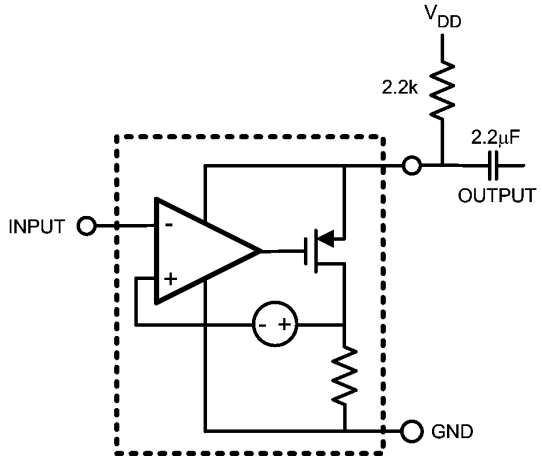
(Typical LMV1012-15, 2.2V supply, R_L = 2.2 kΩ, C = 2.2 µF, V_{IN} = 18 mV_{PP}, unless otherwise specified)

- Supply voltage 2V - 5V
- Supply current <180 µA
- Signal to noise ratio (A-weighted) 60 dB
- Output voltage noise (A-weighted) –89 dBV
- Total harmonic distortion 0.09%
- Voltage gain
  - — LMV1012-07 7.8 dB
  - — LMV1012-15 15.6 dB
  - — LMV1012-20 20.9 dB
  - — LMV1012-25 23.8 dB
- Temperature range –40˚C to 85˚C
- Offered in 4-bump micro SMD packages

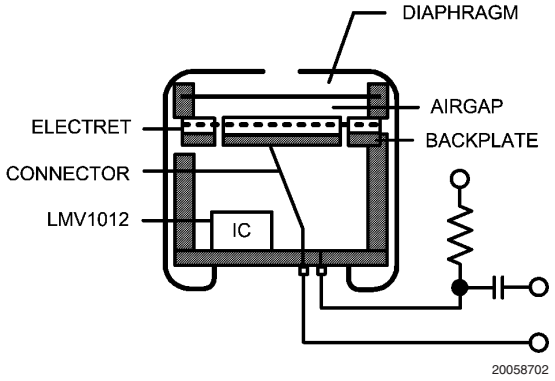
Applications

- Cellular phones
- Headsets
- Mobile communications
- Automotive accessories
- PDAs
- Accessory microphone products

Schematic Diagram



Built-In Gain Electret Microphone



Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

ESD Tolerance (Note 2)	
Human Body Model	2500V
Machine Model	250V
Supply Voltage	
V_{DD} - GND	5.5V
Storage Temperature Range	−65˚C to 150˚C
Junction Temperature (Note 6)	150˚C max
Mounting Temperature	
Infrared or Convection (20 sec.)	235˚C

Operating Ratings (Note 1)

Supply Voltage	2V to 5V
Temperature Range	−40˚C to 85˚C

2.2V Electrical Characteristics (Note 3)

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V_{DD} = 2.2V, V_{IN} = 18 mV, R_L = 2.2 kΩ and C = 2.2 µF. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions		Min (Note 4)	Typ (Note 5)	Max (Note 4)	Units
I_{DD}	Supply Current	V_{IN} = GND	LMV1012-07		139	250 **300**	µA
			LMV1012-15		180	300 **325**	
			LMV1012-20		160	250 **300**	
			LMV1012-25		141	250 **300**	
SNR	Signal to Noise Ratio	f = 1 kHz, V_{IN} = 18 mV, A-Weighted	LMV1012-07		59		dB
			LMV1012-15		60		
			LMV1012-20		61		
			LMV1012-25		61		
V_{IN}	Max Input Signal	f = 1 kHz and THD+N < 1%	LMV1012-07		170		mV_{PP}
			LMV1012-15		100		
			LMV1012-20		50		
			LMV1012-25		28		
V_{OUT}	Output Voltage	V_{IN} = GND	LMV1012-07	1.65 **1.54**	1.90	2.03 **2.09**	V
			LMV1012-15	1.54 **1.48**	1.81	1.94 **2.00**	
			LMV1012-20	1.65 **1.55**	1.85	2.03 **2.13**	
			LMV1012-25	1.65 **1.49**	1.90	2.02 **2.18**	
f_{LOW}	Lower −3dB Roll Off Frequency	R_{SOURCE} = 50Ω			65		Hz
f_{HIGH}	Upper −3dB Roll Off Frequency	R_{SOURCE} = 50Ω			95		kHz
e_n	Output Noise	A-Weighted	LMV1012-07		−96		dBV
			LMV1012-15		−89		
			LMV1012-20		−84		
			LMV1012-25		−82		
THD	Total Harmonic Distortion	f = 1 kHz, V_{IN} = 18 mV	LMV1012-07		0.10		%
			LMV1012-15		0.09		
			LMV1012-20		0.12		
			LMV1012-25		0.15		
C_{IN}	Input Capacitance				2		pF
Z_{IN}	Input Impedance				>1000		GΩ

2.2V Electrical Characteristics (Note 3) (Continued)

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V_{DD} = 2.2V, V_{IN} = 18 mV, R_L = 2.2 kΩ and C = 2.2 µF. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions		Min (Note 4)	Typ (Note 5)	Max (Note 4)	Units
A_V	Gain	f = 1 kHz, R_{SOURCE} = 50Ω	LMV1012-07	6.4 **5.5**	7.8	9.5 **10.0**	dB
			LMV1012-15	14.0 **13.1**	15.6	16.9 **17.5**	
			LMV1012-20	19.5 **17.4**	20.9	22.0 **23.3**	
			LMV1012-25	22.5 **21.4**	23.8	25.0 **25.7**	

5V Electrical Characteristics (Note 3)

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V_{DD} = 5V, V_{IN} = 18 mV, R_L = 2.2 kΩ and C = 2.2 µF. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions		Min (Note 4)	Typ (Note 5)	Max (Note 4)	Units
I_{DD}	Supply Current	V_{IN} = GND	LMV1012-07		158	250 **300**	µA
			LMV1012-15		200	300 **325**	
			LMV1012-20		188	260 **310**	
			LMV1012-25		160	250 **300**	
SNR	Signal to Noise Ratio	f = 1 kHz, V_{IN} = 18 mV, A-Weighted	LMV1012-07		59		dB
			LMV1012-15		60		
			LMV1012-20		61		
			LMV1012-25		61		
V_{IN}	Max Input Signal	f = 1 kHz and THD+N < 1%	LMV1012-07		170		mV_{PP}
			LMV1012-15		100		
			LMV1012-20		55		
			LMV1012-25		28		
V_{OUT}	Output Voltage	V_{IN} = GND	LMV1012-07	4.45 **4.38**	4.65	4.80 **4.85**	V
			LMV1012-15	4.34 **4.28**	4.56	4.74 **4.80**	
			LMV1012-20	4.40 **4.30**	4.58	4.75 **4.85**	
			LMV1012-25	4.45 **4.39**	4.65	4.83 **4.86**	
f_{LOW}	Lower –3dB Roll Off Frequency	R_{SOURCE} = 50Ω			67		Hz
f_{HIGH}	Upper –3dB Roll Off Frequency	R_{SOURCE} = 50Ω			150		kHz
e_n	Output Noise	A-Weighted	LMV1012-07		–96		dBV
			LMV1012-15		–89		
			LMV1012-20		–84		
			LMV1012-25		–82		
THD	Total Harmonic Distortion	f = 1 kHz, V_{IN} = 18 mV	LMV1012-07		0.12		%
			LMV1012-15		0.13		
			LMV1012-20		0.18		
			LMV1012-25		0.21		

5V Electrical Characteristics (Note 3) (Continued)

Unless otherwise specified, all limits guaranteed for T_J = 25˚C, V_{DD} = 5V, V_{IN} = 18 mV, R_L = 2.2 kΩ and C = 2.2 µF. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions		Min (Note 4)	Typ (Note 5)	Max (Note 4)	Units
C_{IN}	Input Capacitance				2		pF
Z_{IN}	Input Impedance				>1000		GΩ
A_V	Gain	f = 1 kHz, R_{SOURCE} = 50Ω	LMV1012-07	6.4 **5.5**	8.1	9.5 **10.7**	dB
			LMV1012-15	14.0 **13.1**	15.6	16.9 **17.5**	
			LMV1012-20	19.2 **17.0**	21.1	22.3 **23.5**	
			LMV1012-25	22.5 **21.2**	23.9	25.0 **25.8**	

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

Note 2: Human Body Model (HBM) is 1.5 kΩ in series with 100 pF.

Note 3: Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.

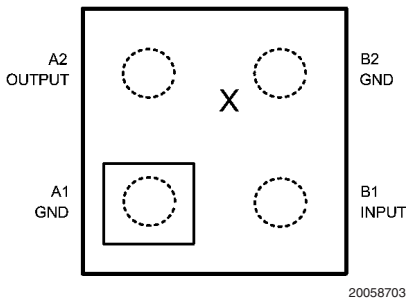
Note 4: All limits are guaranteed by design or statistical analysis.

Note 5: Typical values represent the most likely parametric norm.

Note 6: The maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA} and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

Connection Diagram

4-Bump micro SMD



Top View

Note: - Pin numbers are referenced to package marking text orientation.

- The actual physical placement of the package marking will vary slightly from part to part. The package will designate the date code and will vary considerably. Package marking does not correlate to device type in any way.

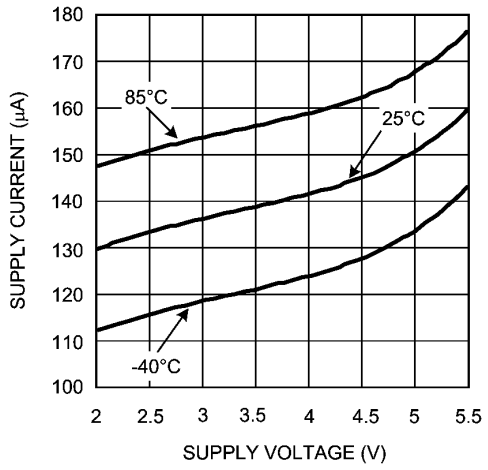
Ordering Information

Package	Part Number	Package Marking	Transport Media	NSC Drawing
4-Bump Extreme Thin micro SMD (0.3 mm max height) lead free only	LMV1012XP-15	Date Code	250 Units Tape and Reel	XPA04HLA
	LMV1012XPX-15		3k Units Tape and Reel	
	LMV1012XP-25		250 Units Tape and Reel	
	LMV1012XPX-25		3k Units Tape and Reel	
4-Bump Ultra-Thin micro SMD (0.4 mm max height) lead free only	LMV1012UP-07	Date Code	250 Units Tape and Reel	UPA04GKA
	LMV1012UPX-07		3k Units Tape and Reel	
	LMV1012UP-15		250 Units Tape and Reel	
	LMV1012UPX-15		3k Units Tape and Reel	
	LMV1012UP-20		250 Units Tape and Reel	
	LMV1012UPX-20		3k Units Tape and Reel	
	LMV1012UP-25		250 Units Tape and Reel	
	LMV1012UPX-25		3k Units Tape and Reel	
4-Bump Thin micro SMD (0.5 mm max height) lead free only	LMV1012TP-07	Date Code	250 Units Tape and Reel	TPA04GKA
	LMV1012TPX-07		3k Units Tape and Reel	
	LMV1012TP-15		250 Units Tape and Reel	
	LMV1012TPX-15		3k Units Tape and Reel	
	LMV1012TP-25		250 Units Tape and Reel	
	LMV1012TPX-25		3k Units Tape and Reel	

Typical Performance Characteristics

Unless otherwise specified, V_S = 2.2V, R_L = 2.2 kΩ, C = 2.2 µF, single supply, T_A = 25˚C

Supply Current vs. Supply Voltage (LMV1012-07)



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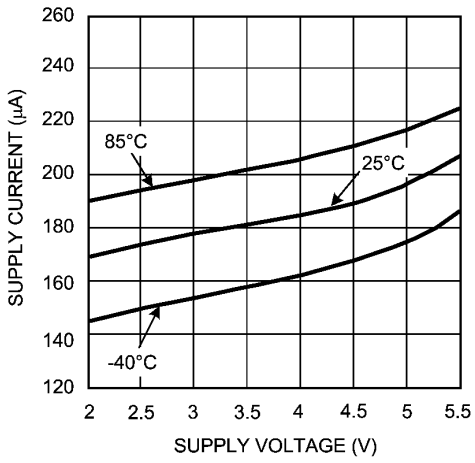
Supply Current vs. Supply Voltage (LMV1012-15)



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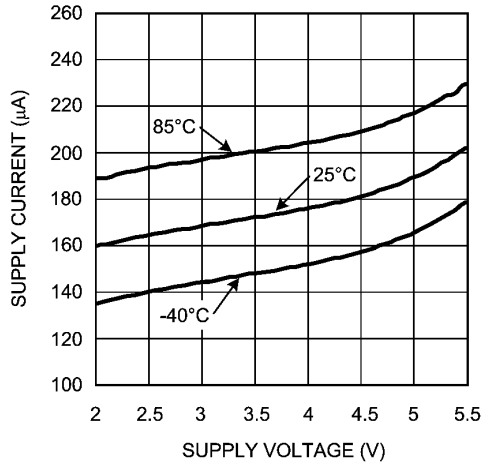
Supply Current vs. Supply Voltage (LMV1012-20)



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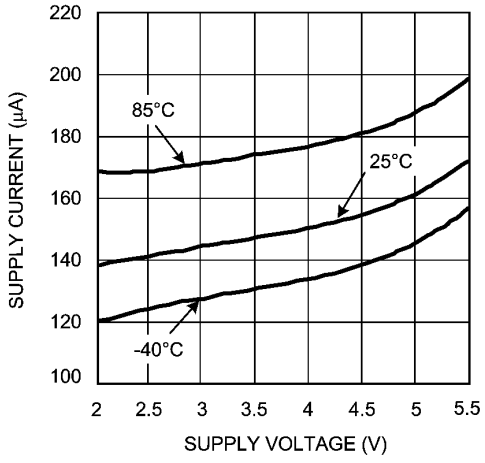
Supply Current vs. Supply Voltage (LMV1012-25)



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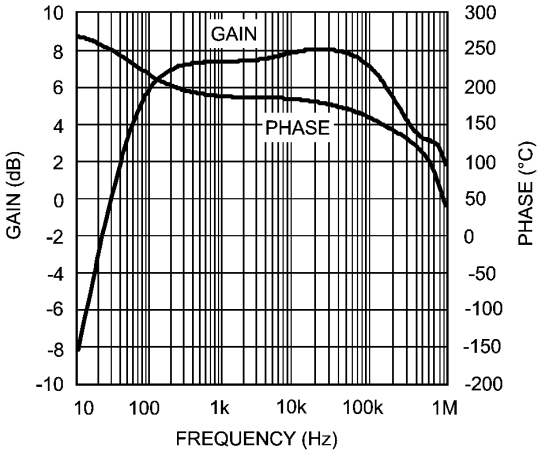
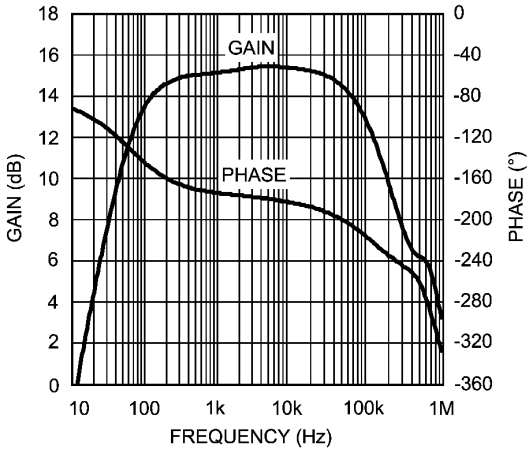
Gain and Phase vs. Frequency (LMV1012-07)



20058714

Gain and Phase vs. Frequency (LMV1012-15)



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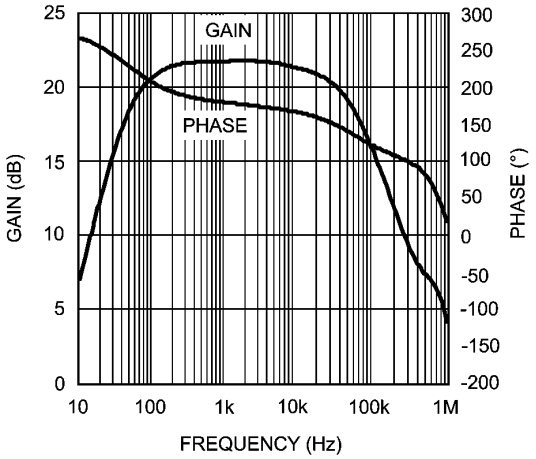
Typical Performance Characteristics

Unless otherwise specified, V_S = 2.2V, R_L = 2.2 kΩ, C = 2.2 µF, single supply, T_A = 25˚C (Continued)

Gain and Phase vs. Frequency (LMV1012-20)



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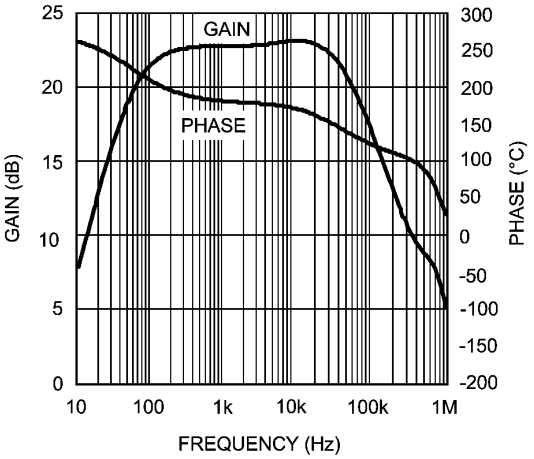
Gain and Phase vs. Frequency (LMV1012-25)



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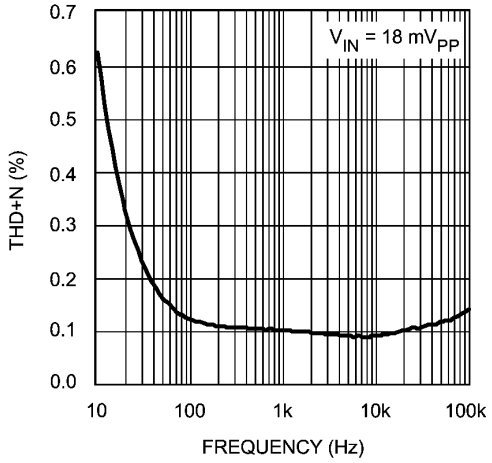
Total Harmonic Distortion vs. Frequency (LMV1012-07)



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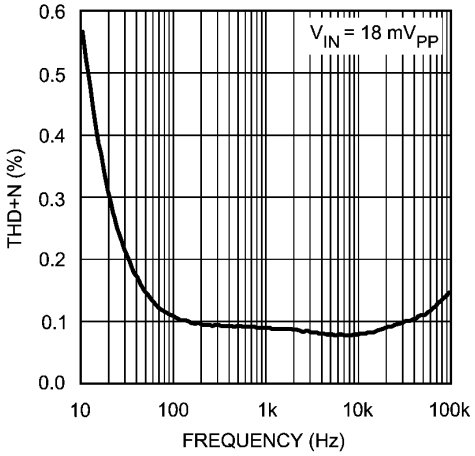
Total Harmonic Distortion vs. Frequency (LMV1012-15)



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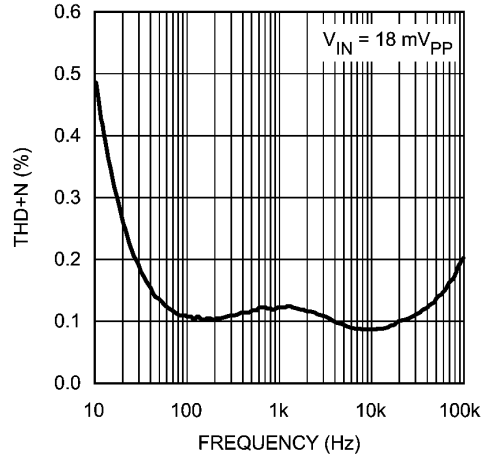
Total Harmonic Distortion vs. Frequency (LMV1012-20)



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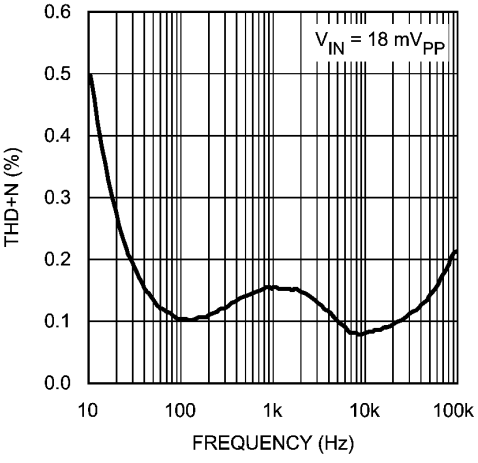
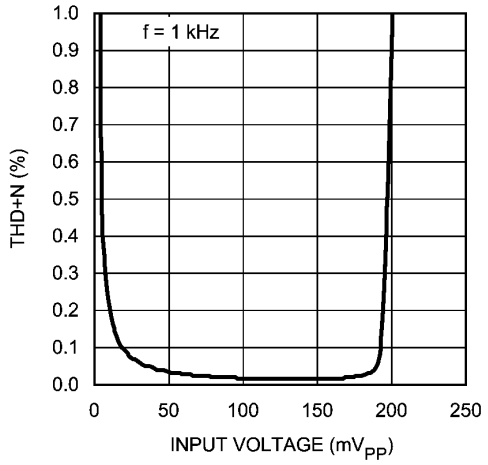
Total Harmonic Distortion vs. Frequency (LMV1012-25)



20058721

Typical Performance Characteristics Unless otherwise specified, V_S = 2.2V, R_L = 2.2 kΩ, C = 2.2 µF, single supply, T_A = 25˚C (Continued)

Total Harmonic Distortion vs. Input Voltage (LMV1012-07)



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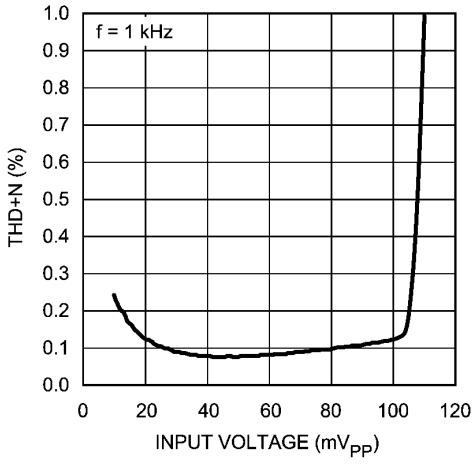
Total Harmonic Distortion vs. Input Voltage (LMV1012-15)



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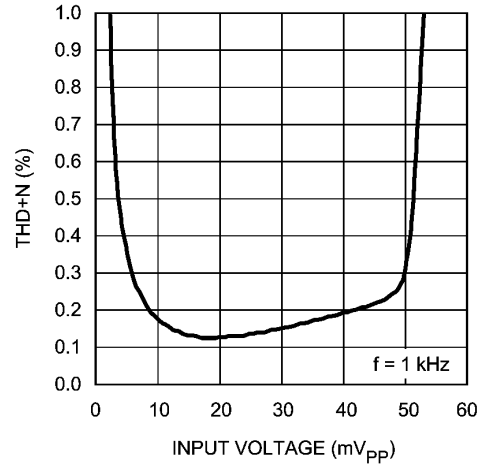
Total Harmonic Distortion vs. Input Voltage (LMV1012-20)



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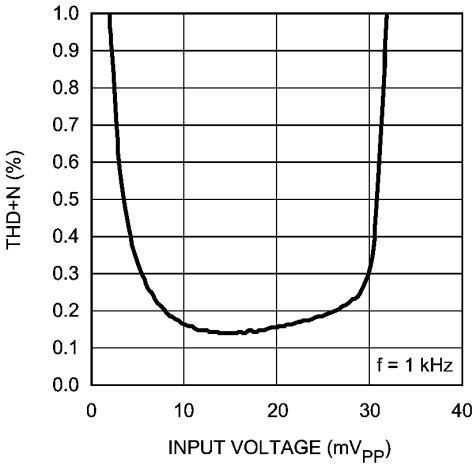
Total Harmonic Distortion vs. Input Voltage (LMV1012-25)



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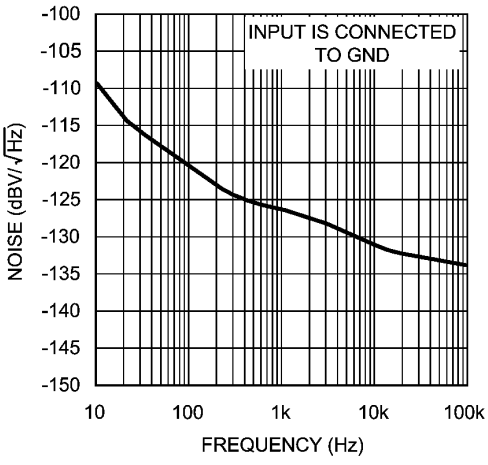
Output Noise vs. Frequency (LMV1012-07)



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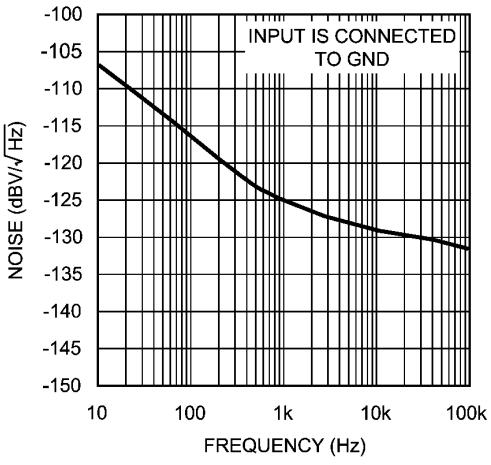
Output Noise vs. Frequency (LMV1012-15)



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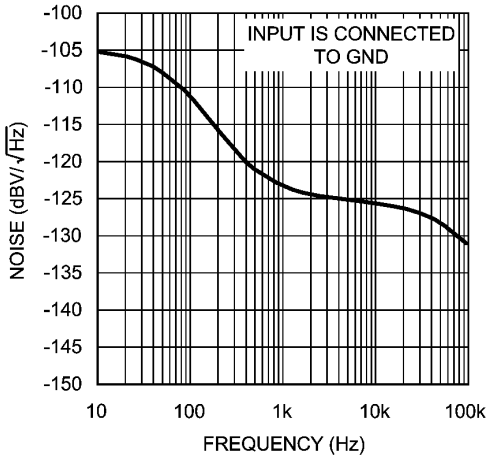
Typical Performance Characteristics Unless otherwise specified, V_S = 2.2V, R_L = 2.2 kΩ, C = 2.2 µF, single supply, T_A = 25˚C (Continued)

Output Noise vs. Frequency (LMV1012-20)



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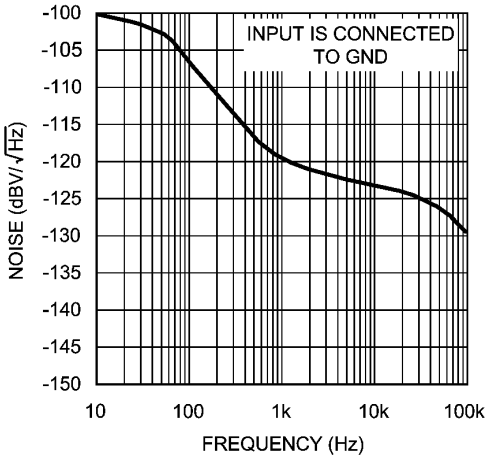
Output Noise vs. Frequency (LMV1012-25)



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Application Section

HIGH GAIN

The LMV1012 series provides outstanding gain versus the JFET and still maintains the same ease of implementation, with improved gain, linearity and temperature stability. A high gain eliminates the need for extra external components.

BUILT IN GAIN

The LMV1012 is offered in 0.3 mm height space saving small 4-pin micro SMD packages in order to fit inside the different size ECM canisters of a microphone. The LMV1012 is placed on the PCB inside the microphone.

The bottom side of the PCB usually shows a bull's eye pattern where the outer ring, which is shorted to the metal can, should be connected to the ground. The center dot on the PCB is connected to the V_{DD} through a resistor. This phantom biasing allows both supply voltage and output signal on one connection.

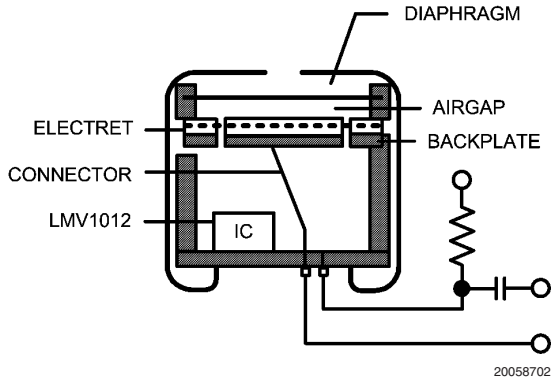


FIGURE 1. Built in Gain

A-WEIGHTED FILTER

The human ear has a frequency range from 20 Hz to about 20 kHz. Within this range the sensitivity of the human ear is not equal for each frequency. To approach the hearing response weighting filters are introduced. One of those filters is the A-weighted filter.

The A-weighted filter is usually used in signal to noise ratio measurements, where sound is compared to device noise. This filter improves the correlation of the measured data to the signal to noise ratio perceived by the human ear.

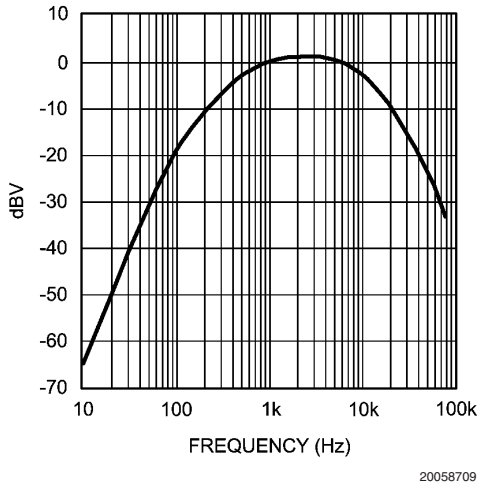


FIGURE 2. A-Weighted Filter

MEASURING NOISE AND SNR

The overall noise of the LMV1012 is measured within the frequency band from 10 Hz to 22 kHz using an A-weighted filter. The input of the LMV1012 is connected to ground with a 5 pF capacitor, as in *Figure 3*. Special precautions in the internal structure of the LMV1012 have been taken to reduce the noise on the output.

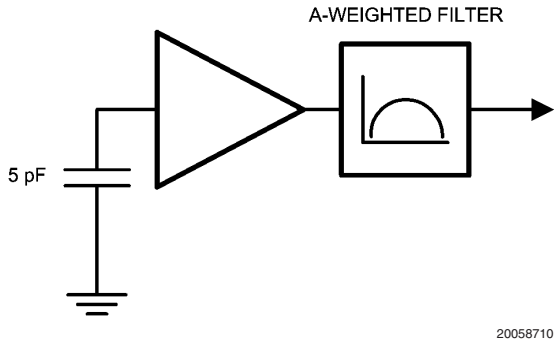


FIGURE 3. Noise Measurement Setup

The signal to noise ratio (SNR) is measured with a 1 kHz input signal of 18 mV_{PP} using an A-weighted filter. This represents a sound pressure level of 94 dB SPL. No input capacitor is connected for the measurement.

SOUND PRESSURE LEVEL

The volume of sound applied to a microphone is usually stated as a pressure level referred to the threshold of hearing of the human ear. The sound pressure level (SPL) in decibels is defined by:

Sound pressure level (dB) = 20 log P_m/P_O

Where,

P_m is the measured sound pressure

P_O is the threshold of hearing (20 µPa)

In order to be able to calculate the resulting output voltage of the microphone for a given SPL, the sound pressure in dB

Application Section (Continued)

SPL needs to be converted to the absolute sound pressure in dBPa. This is the sound pressure level in decibels referred to 1 Pascal (Pa).

The conversion is given by:

dBPa = dB SPL + 20*log 20 µPa

dBPa = dB SPL - 94 dB

Translation from absolute sound pressure level to a voltage is specified by the sensitivity of the microphone. A conventional microphone has a sensitivity of -44 dBV/Pa.

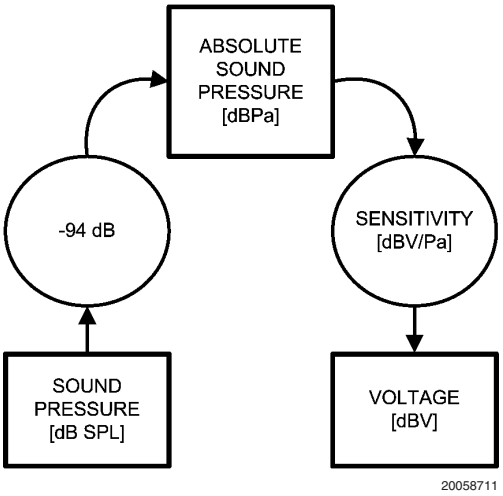


FIGURE 4. dB SPL to dBV Conversion

Example: Busy traffic is 70 dB SPL

V_{OUT} = 70 –94 –44 = –68 dBV

This is equivalent to 1.13 mV_{PP}

Since the LMV1012-15 has a gain of 6 (15.6 dB) over the JFET, the output voltage of the microphone is 6.78 mV_{PP}. By implementing the LMV1012-15, the sensitivity of the microphone is -28.4 dBV/Pa (–44 + 15.6).

LOW FREQUENCY CUT OFF FILTER

To reduce noise on the output of the microphone a low frequency cut off filter has been implemented. This filter reduces the effect of wind and handling noise.

It's also helpful to reduce the proximity effect in directional microphones. This effect occurs when the sound source is very close to the microphone. The lower frequencies are amplified which gives a bass sound. This amplification can cause an overload, which results in a distortion of the signal.

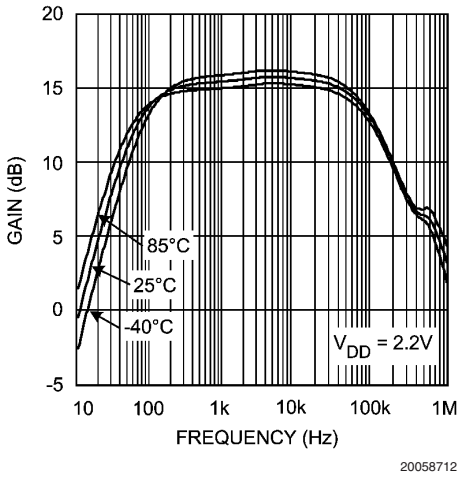


FIGURE 5. LMV1012-15 Gain vs. Frequency Over Temperature

The LMV1012 is optimized to be used in audio band applications. By using the LMV1012, the gain response is flat within the audio band and has linearity and temperature stability *Figure 5*.

NOISE

Noise pick-up by a microphone in cell phones is a well-known problem. A conventional JFET circuit is sensitive for noise pick-up because of its high output impedance, which is usually around 2.2 kΩ.

RF noise is amongst other caused by non-linear behavior. The non-linear behavior of the amplifier at high frequencies, well above the usable bandwidth of the device, causes AM-demodulation of high frequency signals. The AM modulation contained in such signals folds back into the audio band, thereby disturbing the intended microphone signal. The GSM signal of a cell phone is such an AM-modulated signal. The modulation frequency of 216 Hz and its harmonics can be observed in the audio band. This kind of noise is called bumblebee noise.

RF noise caused by a GSM signal can be reduced by connecting two external capacitors to ground, see *Figure 6*. One capacitor reduces the noise caused by the 900 MHz carrier and the other reduces the noise caused by 1800/1900 MHz.

Application Section (Continued)

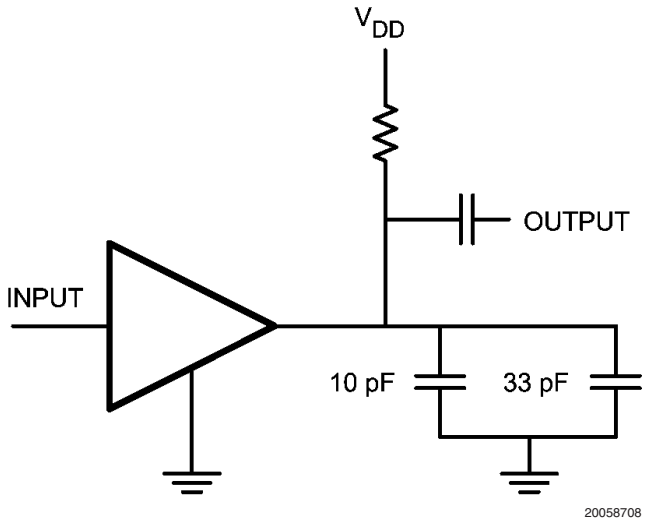
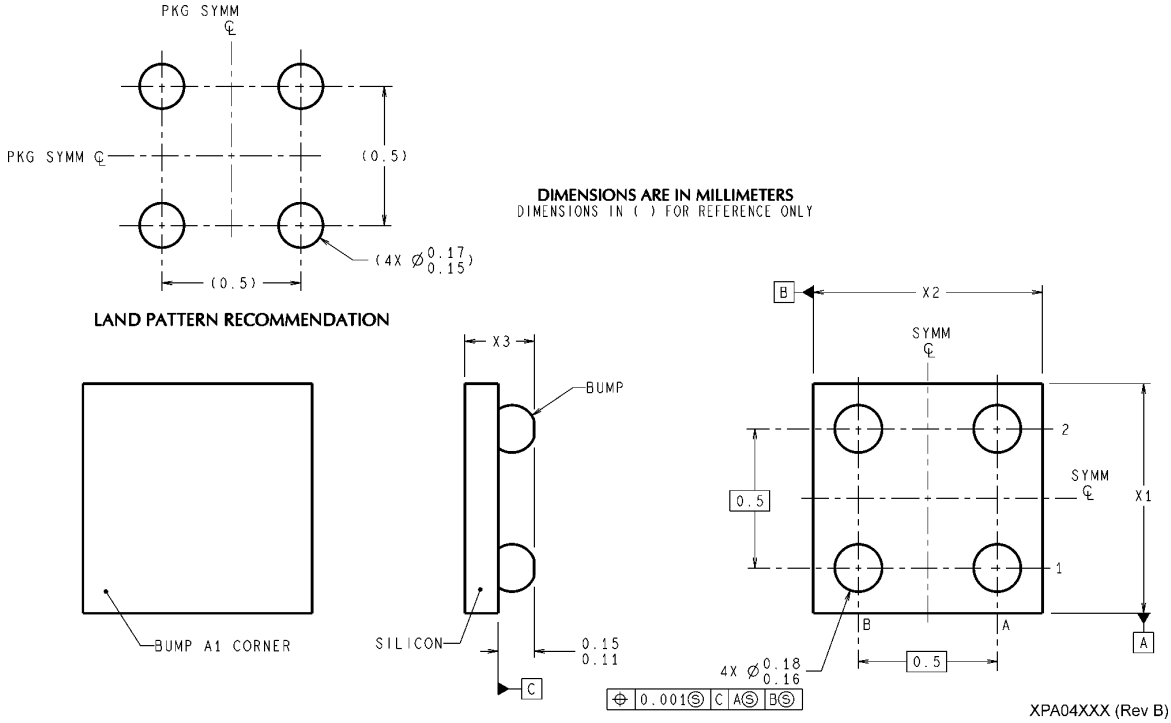


FIGURE 6. RF Noise Reduction

Physical Dimensions inches (millimeters) unless otherwise noted



NOTE: UNLESS OTHERWISE SPECIFIED.

1. FOR SOLDER BUMP COMPOSITION, SEE "SOLDER INFORMATION" IN THE PACKAGING SECTION OF THE NATIONAL SEMICONDUCTOR WEB PAGE (www.national.com).

2. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.

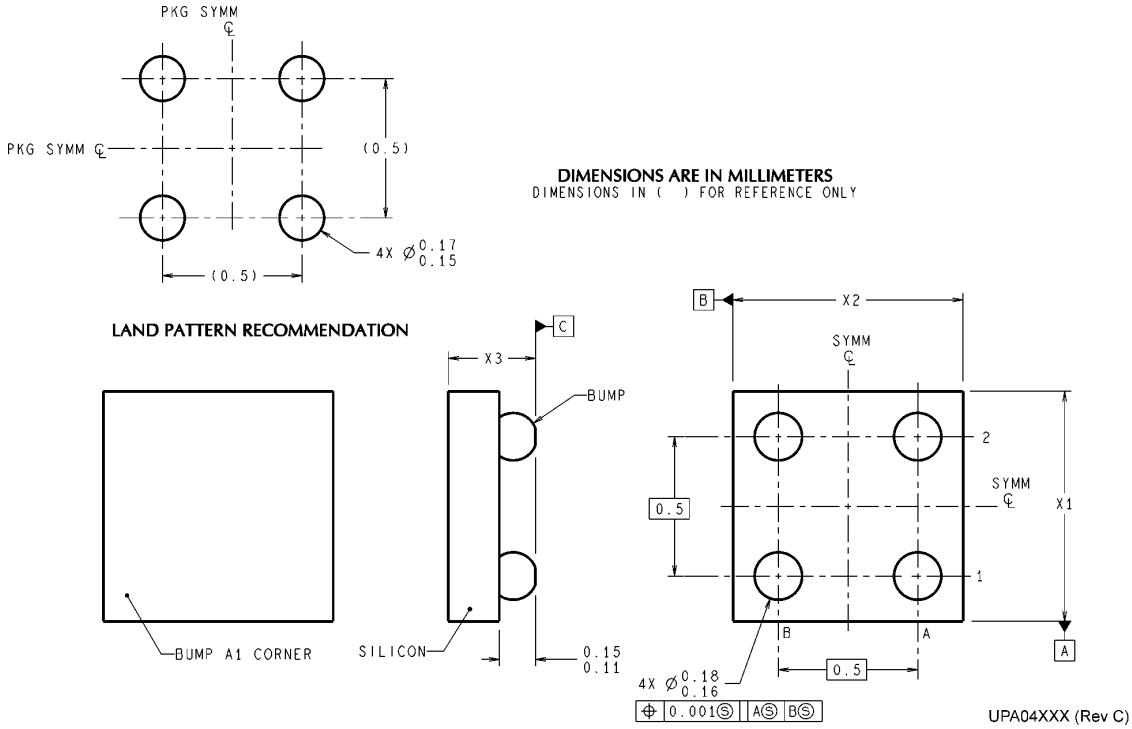
3. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION.

4. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.

5. REFERENCE JEDEC REGISTRATION MO-211. VARIATION CA.

4-Bump Extreme Thin micro SMD
NS Package Number XPA04HLA
X1 = 0.955 mm X2 = 1.031 mm X3 = 0.300 mm

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

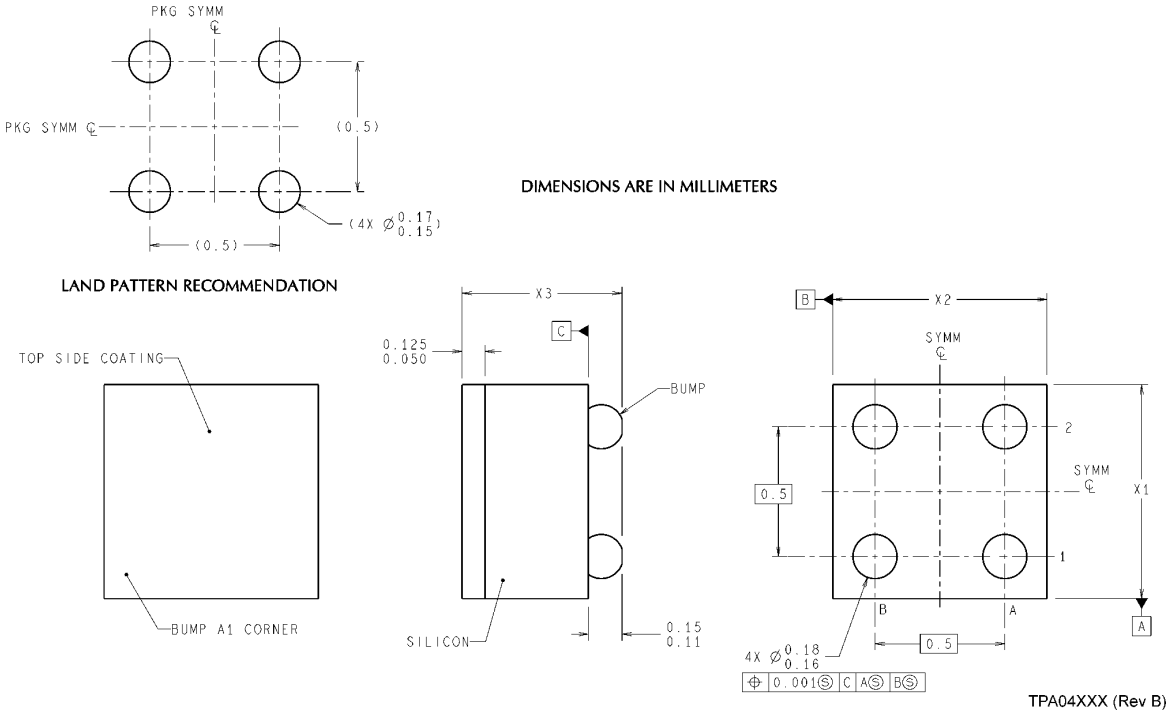


NOTE: UNLESS OTHERWISE SPECIFIED.

1. FOR SOLDER BUMP COMPOSITION, SEE "SOLDER INFORMATION" IN THE PACKAGING SECTION OF THE NATIONAL SEMICONDUCTOR WEB PAGE (www.national.com).
2. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.
3. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION.
4. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.
5. REFERENCE JEDEC REGISTRATION MO-211. VARIATION CA.

4-Bump ULTRA-Thin micro SMD
NS Package Number UPA04GKA
X1 = 0.93 mm X2 = 1.006 mm X3 = 0.400 mm

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTE: UNLESS OTHERWISE SPECIFIED.

1. EPOXY COATING.
2. 63Sn/37Pb EUTECTIC BUMP.
3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.
4. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION PINS ARE NUMBERED COUNTERCLOCKWISE.
5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.
6. REFERENCE JEDEC REGISTRATION MO-211. VARIATION BC.

4-Bump Thin micro SMD
NS Package Number TPA04GKA
X1 = 0.93 mm X2 = 1.006 mm X3 = 0.500 mm

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